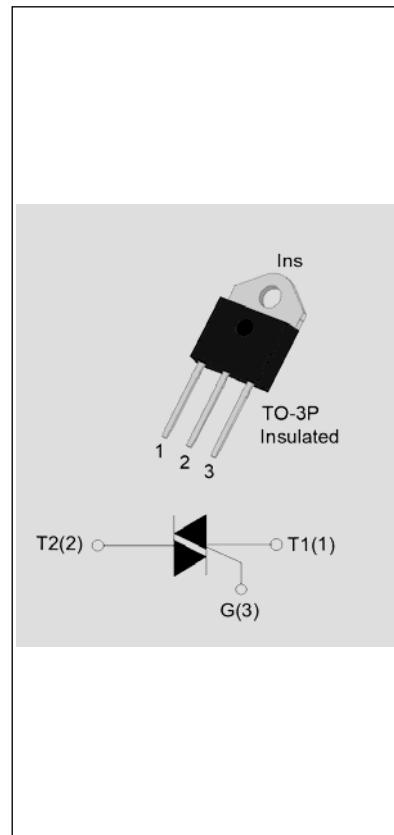




The T3050H-8Z triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Compared to traditional triacs, T3050H-8Z provides a very high switching capability up to junction temperatures of 150°C. By using an internal ceramic pad, T3050H-8Z provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TO-3P is RoHS compliant.



Symbol	Value	Unit
$I_{T(RMS)}$	30	A
V_{DRM}/V_{RRM}	800	V
$I_{GT} / /$	50/50/50	mA

Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-150	
Repetitive peak off-state voltage ($T_j=25^\circ C$)	V_{DRM}	800	V
Repetitive peak reverse voltage ($T_j=25^\circ C$)	V_{RRM}	800	V
RMS on-state current ($T_c = 114^\circ C$)	$I_{T(RMS)}$	30	A
Non repetitive surge peak on-state current (full cycle , $t_p=20ms$, $T_j=25^\circ C$)	I_{TSM}	270	A
Non repetitive surge peak on-state current (full cycle , $t_p=16.6ms$, $T_j=25^\circ C$)		297	
I^2t value for fusing ($t_p=10ms$, $T_j=25^\circ C$)	I^2t	365	A^2s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$, $f=100Hz$, $T_j=150^\circ C$)	dI/dt	100	$A/\mu s$
Peak gate current ($t_p=20\mu s$, $T_j=150^\circ C$)	I_{GM}	4	A



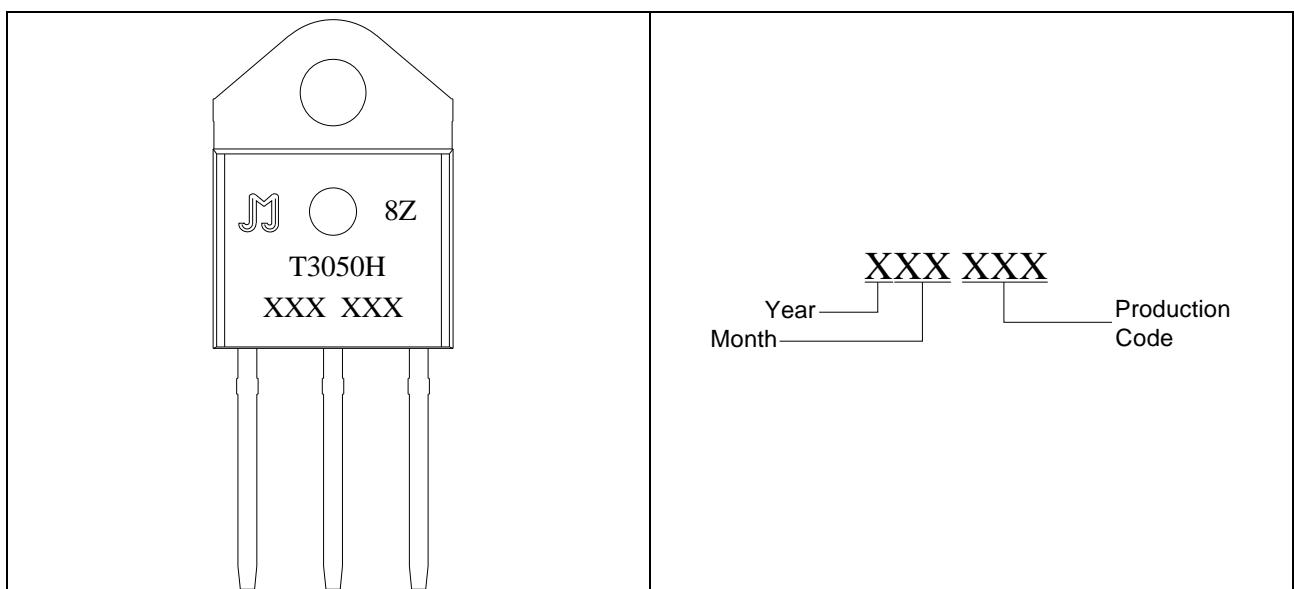
Average gate power dissipation ($T_j=150^\circ C$)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	10	W
Peak pulse voltage ($T_j=25^\circ C$; non-repetitive, off-state; FIG.7)	V_{pp}	1.2	kV

($T_j=25^\circ C$ unless otherwise specified)

I_{GT}	$V_D = 12V$ $R_L = 33\Omega$	- -	MAX.	50	mA
V_{GT}		- -	MAX.	1.3	V
V_{GD}	$V_D = V_{DRM}$ $T_j = 150^\circ C$ $R_L = 3.3K$	- -	MIN.	0.15	V
I_L	$I_G = 1.2I_{GT}$	-	MAX.	80	mA
				90	
I_H	$I_T = 500mA$		MAX.	60	mA

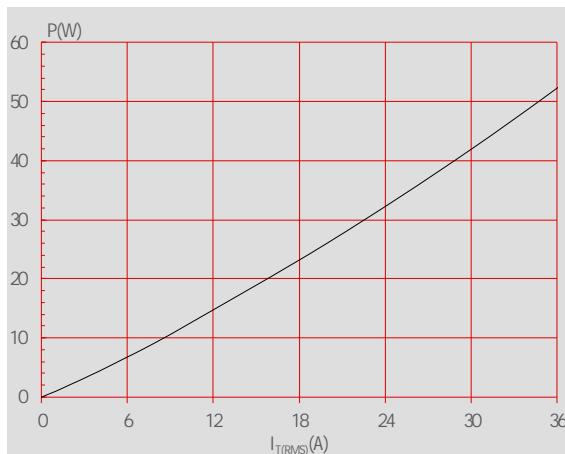


T	30	50	H	-8	Z
Triacs					
	<u>$I_{T(RMS)}:30A$</u>				
		<u>50:IGT1-3 50mA</u>			
				<u>8:V_{DRM} /V_{RRM} 800V</u>	
					<u>High junction temperature</u>

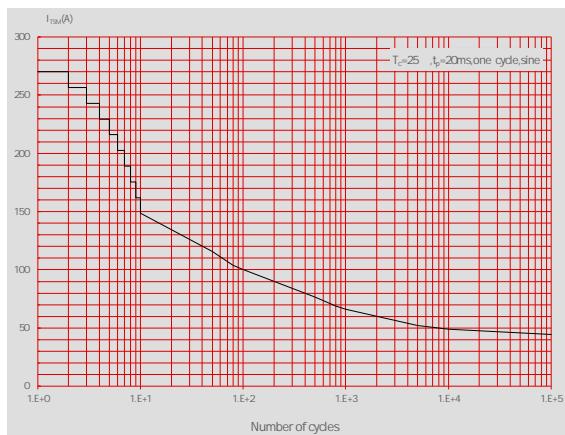




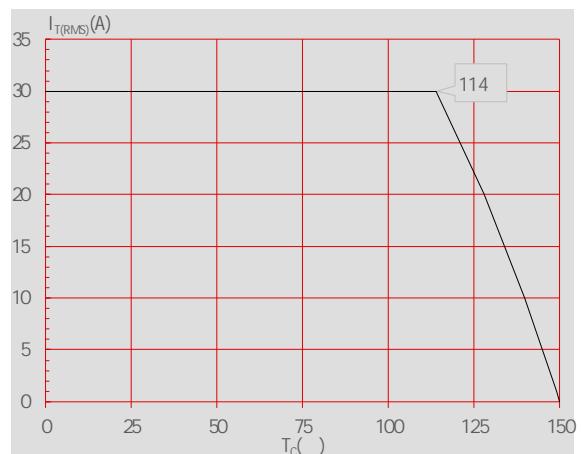
Maximum power dissipation versus RMS on-state current



Surge peak on-state current versus number of cycles



RMS on-state current versus case temperature



On-state characteristics

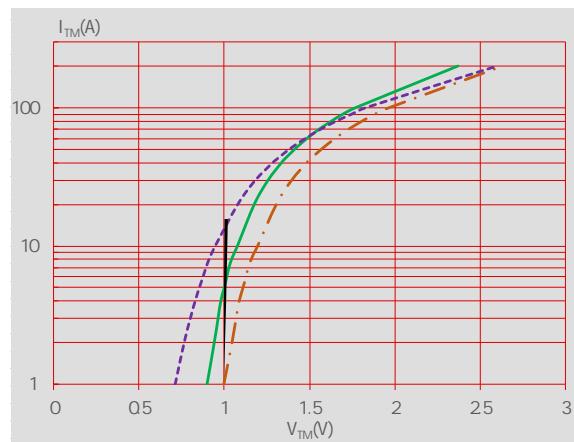
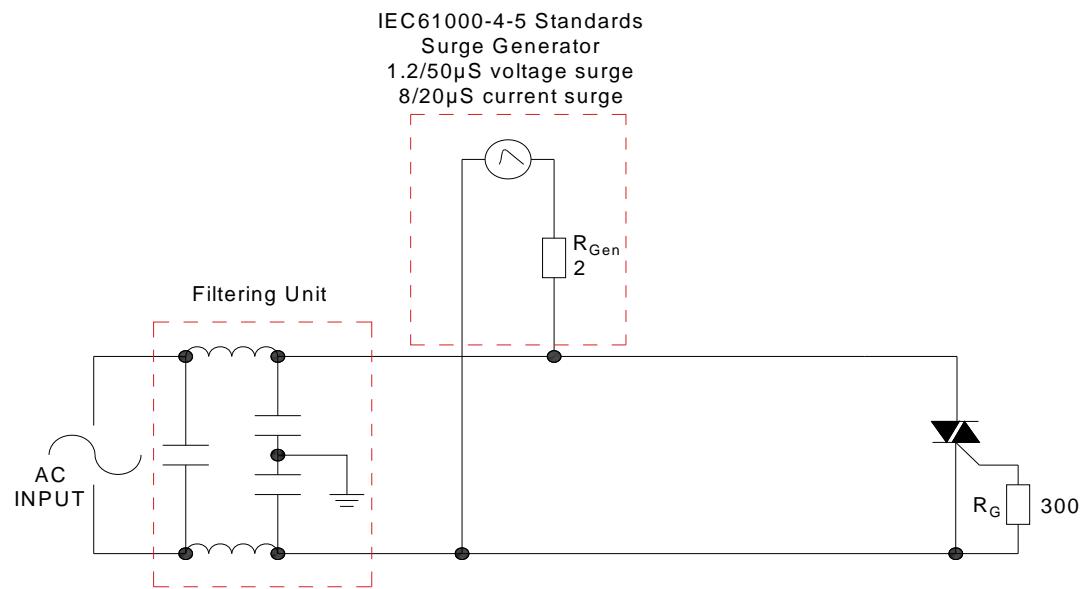




FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



Refer to Instructions for installation of plastic-sealed in-line power devices released by JieJie



Date	Revision	Changes
Apr.10, 2023	A.1.0	Last updated



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